

November 1996

## 3MHz, BiMOS Microprocessor Operational Amplifiers with MOSFET Input/CMOS Output

### Features

- **MOSFET Input Stage provides**
  - Very High  $Z_i = 1.5T\Omega (1.5 \times 10^{12}\Omega)$  (Typ)
  - Very Low  $I_i = 5\text{pA}$  (Typ) at 15V Operation  
=  $2\text{pA}$  (Typ) at 5V Operation
- **Ideal for Single Supply Applications**
- **Common Mode Input Voltage Range Includes Negative Supply Rail; Input Terminals Can be Swung 0.5V Below Negative Supply Rail**
- **CMOS Output Stage Permits Signal Swing to Either (or Both) Supply Rails**
- **CA5260A, CA5260 Have Full Military Temperature Range Guaranteed Specifications for  $V_+ = 5\text{V}$**
- **CA5260A, CA5260 are Guaranteed to Operate Down to 4.5V for AOL**
- **Fully Guaranteed to Operate from -55°C to 125°C at  $V_+ = 5\text{V}$ ,  $V_- = \text{GND}$**

### Applications

- **Ground Referenced Single Supply Amplifiers**
- **Fast Sample-Hold Amplifiers**
- **Long Duration Timers/Monostables**
- **Ideal Interface with Digital CMOS**
- **High Input Impedance Wideband Amplifiers**
- **Voltage Followers (e.g., Follower for Single Supply D/A Converter)**
- **Voltage Regulators (Permits Control of Output Voltage Down to 0V)**
- **Wien Bridge Oscillators**
- **Voltage Controlled Oscillators**
- **Photo Diode Sensor Amplifiers**
- **5V Logic Systems**
- **Microprocessor Interface**

### Description

The CA5260A and CA5260 are integrated-circuit operational amplifiers that combine the advantage of both CMOS and bipolar transistors on a monolithic chip. The CA5260 series circuits are dual versions of the popular CA5160 series. They are designed and guaranteed to operate in microprocessor or logic systems that use +5V supplies.

Gate-protected P-Channel MOSFET (PMOS) transistors are used in the input circuit to provide very-high-input impedance, very-low-input current, and exceptional speed performance. The use of PMOS field-effect transistors in the input stage results in common-mode input-voltage capability down to 0.5V below the negative-supply terminal, an important attribute in single-supply applications.

A complementary-symmetry MOS (CMOS) transistor-pair, capable of swinging the output voltage to within 10mV of either supply-voltage terminal (at very high values of load impedance), is employed as the output circuit.

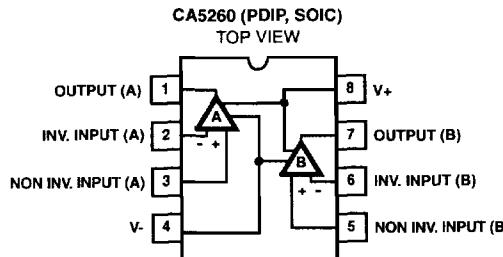
The CA5260 Series circuits operate at supply voltages ranging from 4.5V to 16V, or ±2.25V to ±8V when using split supplies.

The CA5260, CA5260A have guaranteed specifications for 5V operation over the full military temperature range of -55°C to 125°C.

### Ordering Information

PART NUMBER (BRAND)	TEMP. RANGE (°C)	PACKAGE	PKG. NO.
CA5260AE	-55 to 125	8 Ld PDIP	E8.3
CA5260AM (5260A)	-55 to 125	8 Ld SOIC	M8.15
CA5260AM96 (5260A)	-55 to 125	8 Ld SOIC Tape and Reel	M8.15
CA5260E	-55 to 125	8 Ld PDIP	E8.3
CA5260M (5260)	-55 to 125	8 Ld SOIC	M8.15
CA5260M96 (5260)	-55 to 125	8 Ld SOIC Tape and Reel	M8.15

### Pinout







**Electrical Specifications** Each Amplifier at  $T_A = 25^\circ\text{C}$ ,  $V_+ = 15\text{V}$ ,  $V_- = 0\text{V}$ , Unless Otherwise Specified (Continued)

PARAMETER	SYMBOL	TEST CONDITIONS	CA5260			CA5260A			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
Common Mode Input Voltage Range	$V_{ICR}$		10	-0.5 to 12	0	10	-0.5 to 12	0	V
Power Supply Rejection Ratio, $\Delta V_{IO}/\Delta V_\pm$	PSRR	$V_S = \pm 7.5$	-	32	320	-	32	150	$\mu\text{V/V}$
Maximum Output Voltage	$V_{OM^+}$	$R_L = 10\text{k}\Omega$	11	13.3	-	11	13.3	-	V
	$V_{OM^-}$		-	0.002	0.01	-	0.002	0.01	V
	$V_{OM^+}$	$R_L = \infty$	14.99	15	-	14.99	15	-	V
	$V_{OM^-}$		-	0	0.01	-	0	0.01	V
Maximum Output Current	$I_{OM^+}$ (Source)	$V_O = 7.5\text{V}$	12	22	45	12	22	45	mA
	$I_{OM^-}$ (Sink)		12	20	45	12	20	45	mA
Total Supply Current, $R_L = \infty$	$I_+$	$V_O$ (Amp A) = 7.5V $V_O$ (Amp B) = 7.5V	-	9	16.5	-	9	16.5	mA
		$V_O$ (Amp A) = 0V $V_O$ (Amp B) = 0V	-	1.2	4	-	1.2	4	mA
		$V_O$ (Amp A) = 0V $V_O$ (Amp B) = 7.5V	-	5	9.5	-	5	9.5	mA
Input Offset Voltage Temperature Drift	$\Delta V_{IO}/\Delta T$		-	8	-	-	6	-	$\mu\text{V}/^\circ\text{C}$
Crosstalk		$f = 1\text{kHz}$	-	120	-	-	120	-	dB

**Schematic Diagram**